

5.0mm x 6.0mm BI-COLOR SURFACE MOUNT LED LAMP



ATTENTION
OBSERVE PRECAUTIONS
FOR HANDLING

ELECTROSTATIC DISCHARGE SENSITIVE DEVICES AAA5060SYEVGEC

SUPER BRIGHT YELLOW GREEN

Features

- •CHIPS CAN BE CONTROLLED SEPARATELY.
- •SUITABLE FOR ALL SMT ASSEMBLY AND SOLDER PROCESS.
- •AVAILABLE ON TAPE AND REEL.
- •PACKAGE: 500PCS / REEL.
- •RoHS COMPLIANT.

Description

The Super Bright Yellow source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

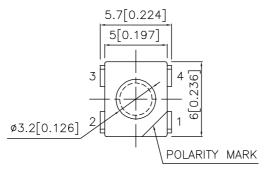
The Green source color devices are made with InGaN on SiC Light Emitting Diode.

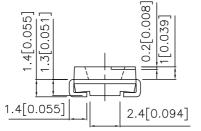
Static electricity and surge damage the LEDS.

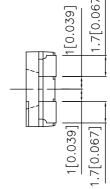
It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs.

All devices, equipment and machinery must be electrically grounded.

Package Dimensions







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Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is $\pm 0.25 (0.01")$ unless otherwise noted.
- 3. Specifications are subject to change without notice.

SPEC NO: DSAD0906 REV NO: V.4 DATE: MAR/05/2005
APPROVED: J. Lu CHECKED: Allen Liu DRAWN: B.H.LI

Selection Guide

Part No.	Dice	Lens Type	lv (mcd) @50mA*30 mA		Viewing Angle
			Min.	Тур.	2 θ 1/2
AAA5060SYEVGEC	SUPER BRIGHT YELLOW (InGaAIP)	WATER OLEAR	280	500	100°
	GREEN (InGaN)	WATER CLEAR	*280	*600	

- 1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value. 2. * Luminous intensity with asterisk is measured at 30mA.

Electrical / Optical Characteristics at T_A=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Yellow Green	592 518		nm	IF=20mA
λD	Dominant Wavelength	Super Bright Yellow Green	590 525		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Yellow Green	20 36		nm	IF=20mA
С	Capacitance	Super Bright Yellow Green	33 50		pF	VF=0V;f=1MHz
VF	Forward Voltage	Super Bright Yellow Green	2.0 3.5	2.5 4.5	V	IF=20mA
I _R	Reverse Current	All		10	uA	V _R = 5V

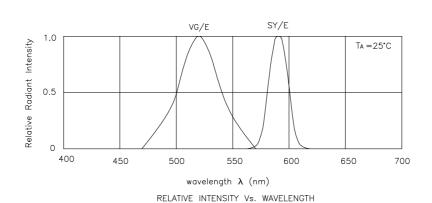
Absolute Maximum Ratings at Ta=25°C

Parameter	Super Bright Yellow	Green	Units	
Power dissipation	125	135	mW	
DC Forward Current	50	30	mA	
Peak Forward Current [1]	200	150	mA	
Reverse Voltage	5	5	V	
Operating / Storage Temperature	-40°C To +85°C			

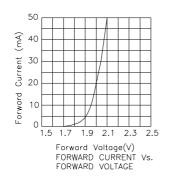
Note:

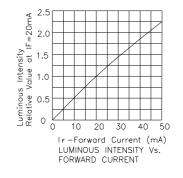
1. 1/10 Duty Cycle, 0.1ms Pulse Width.

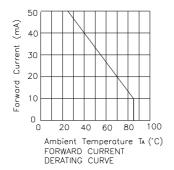
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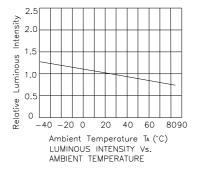


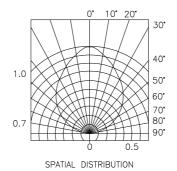
AAA5060SYEVGEC Super Bright Yellow







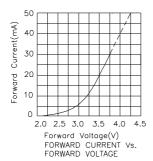


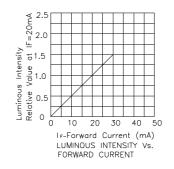


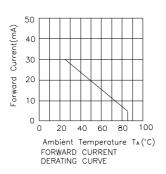
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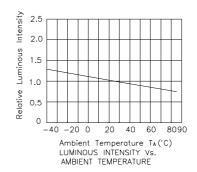
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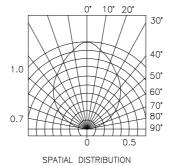
Green







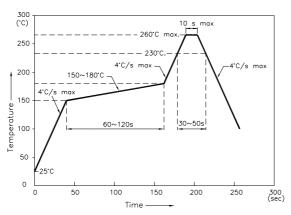




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AAA5060SYEVGEC

Reflow Soldering Profile For Lead-free SMT Process.

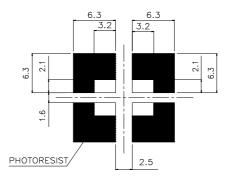


NOTES:

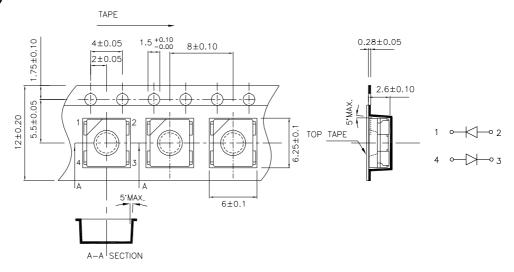
- 1.We recommend the reflow temperature $245^{\circ}C(+/-5^{\circ}C)$.The maximum soldering temperature should be limited to $260^{\circ}C$. 2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
- 3. Number of reflow process shall be 2 times or less.

Recommended Soldering Pattern

(Units: mm)



Tape Specifications (Units: mm)



Remarks:

If there is sorting requirement (eg. forward voltage, luminous intensity or wavelength), the condition as follows:

- 1. Wavelength: +/-1nm (Test condition is based on the sorting standard).
- 2.Luminous intensity: +/-15% (Test condition is based on the sorting standard).
- 3. Forward voltage: +/-0.1V (Test condition is based on the sorting standard).

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